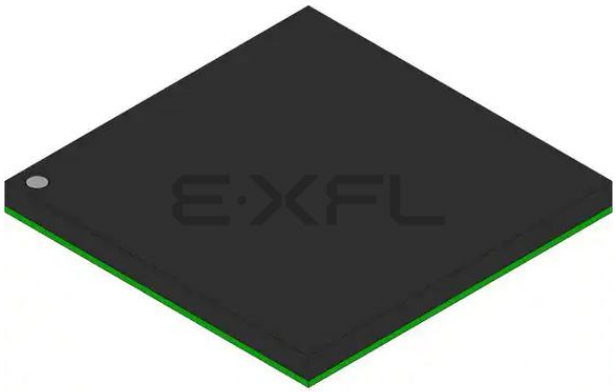

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Understanding Embedded - Microprocessors

Embedded microprocessors are specialized computing chips designed to perform specific tasks within an embedded system. Unlike general-purpose microprocessors found in personal computers, embedded microprocessors are tailored for dedicated functions within larger systems, offering optimized performance, efficiency, and reliability. These microprocessors are integral to the operation of countless electronic devices, providing the computational power necessary for controlling processes, handling data, and managing communications.

Applications of Embedded - Microprocessors

Embedded microprocessors are utilized across a broad spectrum of applications, making them indispensable in

Details	
Product Status	Active
Core Processor	ARM926EJ-S
Number of Cores/Bus Width	1 Core, 32-Bit
Speed	266MHz
Co-Processors/DSP	-
RAM Controllers	SDRAM
Graphics Acceleration	No
Display & Interface Controllers	Keypad, LCD
Ethernet	-
SATA	-
USB	USB 1.x (2)
Voltage - I/O	1.8V, 3V
Operating Temperature	0°C ~ 70°C (TA)
Security Features	-
Package / Case	289-LFBGA
Supplier Device Package	289-MAPBGA (14x14)
Purchase URL	https://www.e-xfl.com/pro/item?MUrl=&PartUrl=mc9328mx21svk

Table 2. i.MX21S Signal Descriptions

Signal Name	Function/Notes
External Bus/Chip Select (EIM)	
A [25:0]	Address bus signals
D [31:0]	Data bus signals
$\overline{EB0}$	MSB Byte Strobe—Active low external enable byte signal that controls D [31:24], shared with SDRAM DQM0.
$\overline{EB1}$	Byte Strobe—Active low external enable byte signal that controls D [23:16], shared with SDRAM DQM1.
$\overline{EB2}$	Byte Strobe—Active low external enable byte signal that controls D [15:8], shared with SDRAM DQM2 and PCMCIA $\overline{PC\_REG}$.
$\overline{EB3}$	LSB Byte Strobe—Active low external enable byte signal that controls D [7:0], shared with SDRAM DQM3 and PCMCIA $\overline{PC\_IORD}$.
$\overline{OE}$	Memory Output Enable—Active low output enables external data bus, shared with PCMCIA $\overline{PC\_IOWR}$.
$\overline{CS}$ [5:0]	Chip Select—The chip select signals $\overline{CS}$ [3:2] are multiplexed with $\overline{CSD}$ [1:0] and are selected by the Function Multiplexing Control Register (FMCR) in the System Control chapter. By default $\overline{CSD}$ [1:0] is selected. DTACK is multiplexed with $\overline{CS4}$.
$\overline{ECB}$	Active low input signal sent by flash device to the EIM whenever the flash device must terminate an on-going burst sequence and initiate a new (long first access) burst sequence.
$\overline{LBA}$	Active low signal sent by flash device causing the external burst device to latch the starting burst address.
BCLK	Clock signal sent to external synchronous memories (such as burst flash) during burst mode.
$\overline{RW}$	$\overline{RW}$ signal—Indicates whether external access is a read (high) or write (low) cycle. This signal is also shared with the PCMCIA $\overline{PC\_WE}$.
DTACK	DTACK signal—External input data acknowledge signal, multiplexed with $\overline{CS4}$.
Bootstrap	
BOOT [3:0]	System Boot Mode Select—The operational system boot mode upon system reset is determined by the settings of these pins. To hardwire these inputs low, terminate with a 1 KΩ resister to ground. For a logic high, terminate with a 1 KΩ resistor to VDDA. Do not change the state of these inputs after power-up. Boot 3 should always be tied to logic low.
SDRAM Controller	
SDBA [4:0]	SDRAM non-interleave mode bank address signals. These signals are multiplexed with address signals A[20:16].
SDIBA [3:0]	SDRAM interleave addressing mode bank address signals. These signals are multiplexed with address signals A[24:21].
MA [11:0]	SDRAM address signals. MA[9:0] are multiplexed with address signals A[10:1].
DQM [3:0]	SDRAM data qualifier mask multiplexed with $\overline{EB}$[3:0]. DQM3 corresponds to D[31:24], DQM2 corresponds to D[23:16], DQM1 corresponds to D[15:8], and DQM0 corresponds to D[7:0].
$\overline{CSD0}$	SDRAM Chip Select signal. This signal is multiplexed with the $\overline{CS2}$ signal. This signal is selectable by programming the Function Multiplexing Control Register in the System Control chapter.
$\overline{CSD1}$	SDRAM Chip Select signal. This signal is multiplexed with the $\overline{CS3}$ signal. This signal is selectable by programming the Function Multiplexing Control Register in the System Control chapter.
$\overline{RAS}$	SDRAM Row Address Select signal.

Table 2. i.MX21S Signal Descriptions (Continued)

Signal Name	Function/Notes
RTCK	JTAG Return Clock used to enhance stability of JTAG debug interface devices. This signal is multiplexed with 1-Wire, therefore using 1-Wire renders RTCK unusable and vice versa.
LCD Controller	
LD [17:0]	LCD Data Bus—All LCD signals are driven low after reset and when LCD is off. LD[15:0] signals are multiplexed with SLCDC1_DAT[15:0] from SLCDC1. LD[16] is multiplexed with $\overline{\text{EXT\_DMAGRANT}}$.
FLM_VSYNC (or simply referred to as VSYNC)	Frame Sync or Vsync—This signal also serves as the clock signal output for gate driver (dedicated signal SPS for Sharp panel HR-TFT).
LP_HSYNC (or simply referred to as HSYNC)	Line Pulse or HSync
LSCLK	Shift Clock.
OE_ACD	Alternate Crystal Direction/Output Enable.
CONTRAST	This signal is used to control the LCD bias voltage as contrast control.
SPL_SPR	Sampling start signal for left and right scanning. This signal is multiplexed with the SLCDC1_CLK.
PS	Control signal output for source driver (Sharp panel dedicated signal). This signal is multiplexed with the SLCDC1_CS.
CLS	Start signal output for gate driver. This signal is invert version of PS (Sharp panel dedicated signal). This signal is multiplexed with the SLCDC1_RS.
REV	Signal for common electrode driving signal preparation (Sharp panel dedicated signal). This signal is multiplexed with SLCDC1_D0.
Smart LCD Controller	
SLCDC1_CLK	SLCDC Clock output signal. This signal is multiplexed and available at 2 alternate locations. These are SPL_SPR and SD2_CLK signals of LCDC and SD2, respectively.
SLCDC1_CS	SLCDC Chip Select output signal. This signal is multiplexed and available at 2 alternate signal locations. These are PS and SD2_CMD signals of LCDC and SD2, respectively.
SLCDC1_RS	SLCDC Register Select output signal. This signal is multiplexed and available at 2 alternate signal locations. These are CLS and SD2_D3 signals of LCDC and SD2, respectively.
SLCDC1_D0	SLCDC serial data output signal. This signal is multiplexed and available at 2 alternate signal locations. These are and REV and SD2_D2 signals of LCDC and SD2, respectively. This signal is inactive when a parallel data interface is used.
SLCDC1_DAT[15:0]	SLCDC Data output signals for connection to a parallel SLCD panel interface. These signals are multiplexed with LD[15:0] while an alternate 8-bit SLCD muxing is available on LD[15:8]. Further alternate muxing of these signals are available on some of the USB OTG and USBH1 signals.
SLCDC2_CLK	SLCDC Clock input signal for pass through to SLCD device. This signal is multiplexed with SSI3_CLK signal from SSI3.
SLCDC2_CS	SLCDC Chip Select input signal for pass through to SLCD device. This signal is multiplexed with SSI3_TXD signal from SSI3.
SLCDC2_RS	SLCDC Register Select input signal for pass through to SLCD device. This signal is multiplexed with SSI3_RXD signal from SSI3.
SLCDC2_D0	SLCD Data input signal for pass through to SLCD device. This signal is multiplexed with SSI3_FS signal from SSI3.

Table 5. DC Characteristics (Continued)

Parameter	Symbol	Test Conditions	Min	Typ[1]	Max	Units
Low-level output current, fast I/O	I_{OL_F}	V_{out}=0.2NVDD1 DSCR[2] = 000 DSCR = 001 DSCR = 011 DSCR = 111	 3.5 4.5 5.5 6.5	–	–	mA
Schmitt trigger Positive–input threshold	V_T +	–	–	–	2.15	V
Schmitt trigger Negative–input threshold	V_T -		0.75	–	–	V
Hysteresis	V_{HYS}	–	–	0.3	–	V
Input leakage current (no pull-up or pull-down)	I_{in}	V_{in} = 0 or NVDD	–	–	±1	µA
I/O leakage current	I_{OZ}	$V_{I/O}$ = NVDD or 0 I/O = High impedance state	–	–	±5	µA

1. Data labeled Typical is not guaranteed, but is intended as an indication of the IC's potential performance.
2. For DSCR definition refer to the System Control chapter in the reference manual.

Table 6 shows the input and output capacitance for the device.

Table 6. Input/Output Capacitance

Parameter	Symbol	Min	Typ	Max	Units
Input capacitance	C_i	_	_	5	pF
Output capacitance	C_o	_	_	5	pF

Table 7 shows the power consumption for the device.

Table 7. Power Consumption

ID	Parameter	Conditions	Symbol	Typ	Max	Units
1	Run Current	QVDD = QVDDX = 1.65 V, NVDD1 = 1.8 V. NVDD2 through NVDD6 = VDDA = 3.1V. Core = 266 MHz, System = 133 MHz. MPEG4 Playback (QVGA) from MMC/SD card, 30fps, 44.1kHz audio.	I_{QVDD} + I_{QVDDX}	120	–	mA
			I_{NVDD1}	8	–	mA
			I_{NVDD2} through I_{NVDD6} + I_{VDDA}	6.6	–	mA
2	Sleep Current	Standby current with Well Biasing System enabled. Well Bias Control Register (WBCR) must be set as follows: WBCR: CRM_WBS bits = 01 CRM_WBFA bit = 1 CRM_WBM bits = 001 CRM_SPA_SEL bit = 1 FMCR bit = 1 For WBCR definition refer to System Control Chapter in the reference manual.	**I_{STBY}**			
			QVDD = QVDDX = 1.65V, TA[1]	–	3.0	mA
			QVDD = QVDDX = 1.65V, 25°	–	700	µA
			QVDD = QVDDX = 1.55V, 25°	320	–	µA

1. TA = 70°C for suffixes VK, VM, DVK, DVM, and SVK. TA = 85°C for suffixes CVK, CVM, and SCVK.

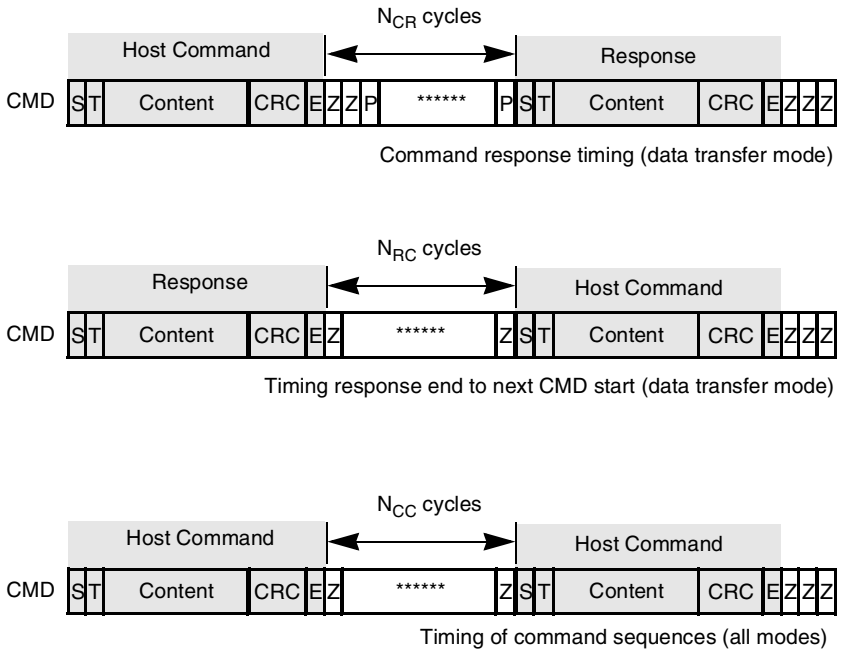


Figure 19. Timing Diagrams at Data Transfer Mode

Figure 20 shows basic read operation timing. In a read operation, the sequence starts with a single block read command (which specifies the start address in the argument field). The response is sent on the SD_CMD lines as usual. Data transmission from the card starts after the access time delay N_{AC}, beginning from the last bit of the read command. If the system is in multiple block read mode, the card sends a continuous flow of data blocks with distance N_{AC} until the card sees a stop transmission command. The data stops two clock cycles after the end bit of the stop command.

Table 23. Timing Values for Figure 18 through Figure 22 (Continued)

Parameter	Symbol	Minimum	Maximum	Unit
Command read cycle	NRC	8	–	Clock cycles
Command-command cycle	NCC	8	–	Clock cycles
Command write cycle	NWR	2	–	Clock cycles
Stop transmission cycle	NST	2	2	Clock cycles
TAAC: Data read access time -1 defined in CSD register bit[119:112] NSAC: Data read access time -2 in CLK cycles (NSAC·100) defined in CSD register bit[111:104]				

3.11.2 SDIO-IRQ and ReadWait Service Handling

In SDIO, there is a 1-bit or 4-bit interrupt response from the SDIO peripheral card. In 1-bit mode, the interrupt response is simply that the SD_DAT[1] line is held low. The SD_DAT[1] line is not used as data in this mode. The memory controller generates an interrupt according to this low and the system interrupt continues until the source is removed (SD_DAT[1] returns to its high level).

In 4-bit mode, the interrupt is less simple. The interrupt triggers at a particular period called the *Interrupt Period* during the data access, and the controller must sample SD_DAT[1] during this short period to determine the IRQ status of the attached card. The interrupt period only happens at the boundary of each block (512 bytes).

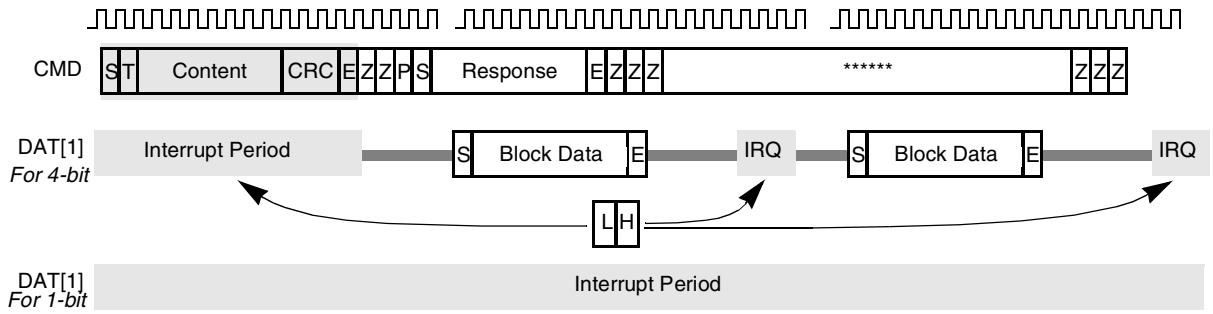


Figure 23. SDIO IRQ Timing Diagram

ReadWait is another feature in SDIO that allows the user to submit commands during the data transfer. In this mode, the block temporarily pauses the data transfer operation counter and related status, yet keeps the clock running, and allows the user to submit commands as normal. After all commands are submitted, the user can switch back to the data transfer operation and all counter and status values are resumed as access continues.

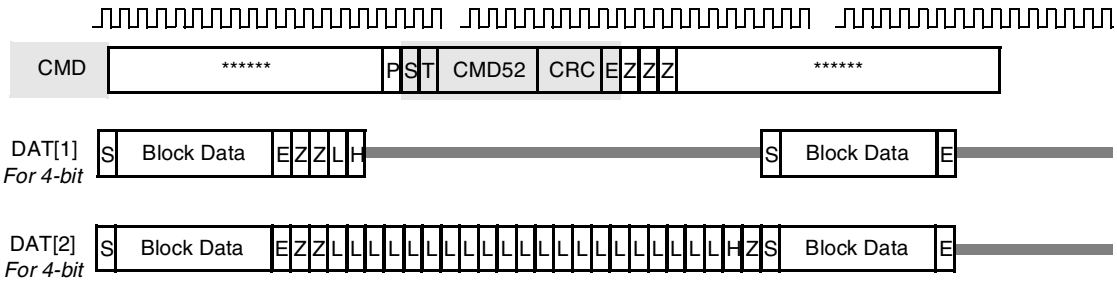


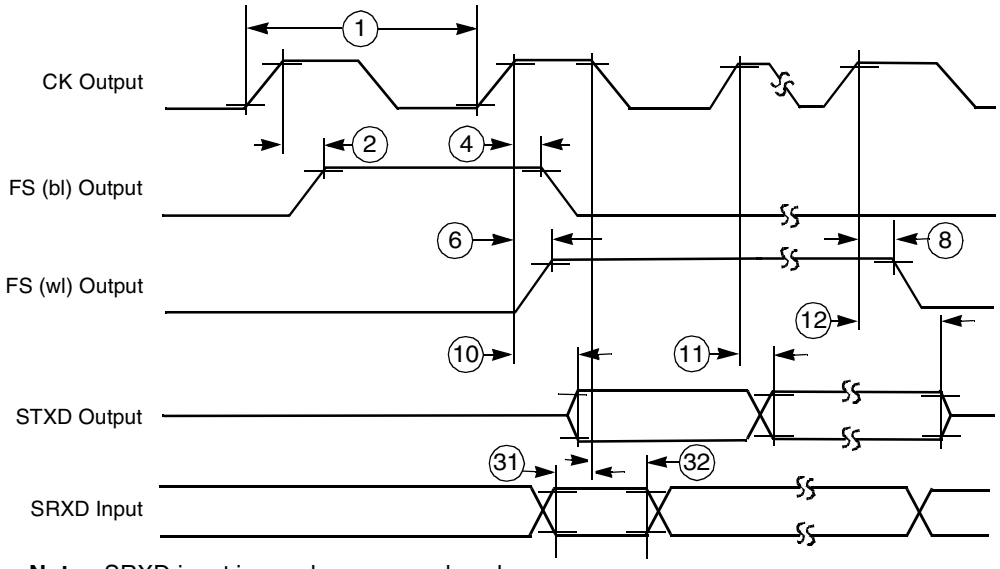
Figure 24. SDIO ReadWait Timing Diagram

3.15 Synchronous Serial Interface

The transmit and receive sections of the SSI can be synchronous or asynchronous. In synchronous mode, the transmitter and the receiver use a common clock and frame synchronization signal. In asynchronous mode, the transmitter and receiver each have their own clock and frame synchronization signals. Continuous or gated clock mode can be selected. In continuous mode, the clock runs continuously. In gated clock mode, the clock functions only during transmission. The internal and external clock timing diagrams are shown in Figure 34 through Figure 37.

Normal or network mode can also be selected. In normal mode, the SSI functions with one data word of I/O per frame. In network mode, a frame can contain between 2 and 32 data words. Network mode is typically used in star or ring-time division multiplex networks with other processors or codecs, allowing interface to time division multiplexed networks without additional logic. Use of the gated clock is not allowed in network mode. These distinctions result in the basic operating modes that allow the SSI to communicate with a wide variety of devices.

The SSI can be connected to 4 set of ports, SAP, SSI1, SSI2 and SSI3.



Note: SRXD input in synchronous mode only.

Figure 34. SSI Transmitter Internal Clock Timing Diagram

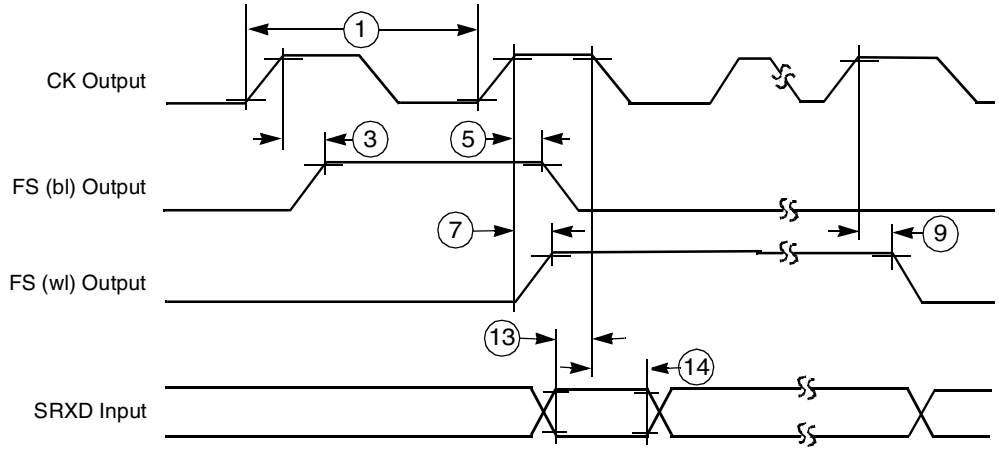
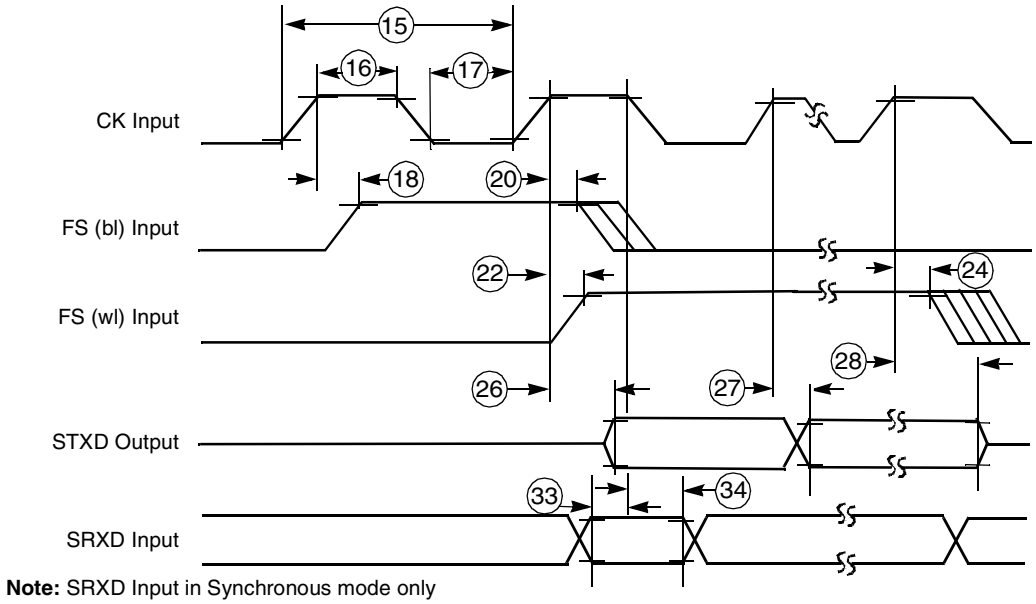


Figure 35. SSI Receiver Internal Clock Timing Diagram



Note: SRXD Input in Synchronous mode only

Figure 36. SSI Transmitter External Clock Timing Diagram

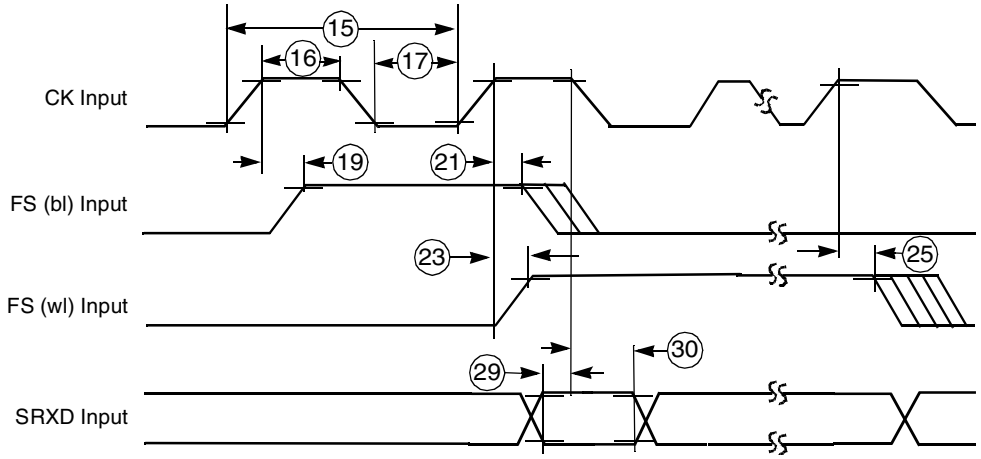


Figure 37. SSI Receiver External Clock Timing Diagram

Table 29. SSI to SAP Ports Timing Parameters (Continued)

Ref No.	Parameter	1.8 V ± 0.1 V		3.0 V ± 0.3 V		Unit
		Minimum	Maximum	Minimum	Maximum	
Synchronous Internal Clock Operation (SAP Ports)						
31	SRXD setup before (Tx) CK falling	23.00	–	21.41	–	ns
32	SRXD hold after (Tx) CK falling	0	–	0	–	ns
Synchronous External Clock Operation (SAP Ports)						
33	SRXD setup before (Tx) CK falling	1.20	–	0.88	–	ns
34	SRXD hold after (Tx) CK falling	0	–	0	–	ns

1. All the timings for the SSI are given for a non-inverted serial clock polarity (TSCKP/RSCKP = 0) and a non-inverted frame sync (TFSI/RFSI = 0). If the polarity of the clock and/or the frame sync have been inverted, all the timing remains valid by inverting the clock signal STCK/SRCK and/or the frame sync STFS/SRFS shown in the tables and in the figures.

Table 30. SSI to SSI1 Ports Timing Parameters

Ref No.	Parameter	1.8 V ± 0.1 V		3.0 V ± 0.3 V		Unit
		Minimum	Maximum	Minimum	Maximum	
Internal Clock Operation[1] (SSI1 Ports)						
1	(Tx/Rx) CK clock period[1]	90.91	–	90.91	–	ns
2	(Tx) CK high to FS (bl) high	-0.68	-0.15	-0.68	-0.15	ns
3	(Rx) CK high to FS (bl) high	-0.96	-0.27	-0.96	-0.27	ns
4	(Tx) CK high to FS (bl) low	-0.68	-0.15	-0.68	-0.15	ns
5	(Rx) CK high to FS (bl) low	-0.96	-0.27	-0.96	-0.27	ns
6	(Tx) CK high to FS (wl) high	-0.68	-0.15	-0.68	-0.15	ns
7	(Rx) CK high to FS (wl) high	-0.96	-0.27	-0.96	-0.27	ns
8	(Tx) CK high to FS (wl) low	-0.68	-0.15	-0.68	-0.15	ns
9	(Rx) CK high to FS (wl) low	-0.96	-0.27	-0.96	-0.27	ns
10	(Tx) CK high to STXD valid from high impedance	-1.68	-0.36	-1.68	-0.36	ns
11a	(Tx) CK high to STXD high	-1.68	-0.36	-1.68	-0.36	ns
11b	(Tx) CK high to STXD low	-1.68	-0.36	-1.68	-0.36	ns
12	(Tx) CK high to STXD high impedance	-1.58	-0.31	-1.58	-0.31	ns
13	SRXD setup time before (Rx) CK low	20.41	–	20.41	–	ns
14	SRXD hold time after (Rx) CK low	0	–	0	–	ns
External Clock Operation (SSI1 Ports)						
15	(Tx/Rx) CK clock period[1]	90.91	–	90.91	–	ns
16	(Tx/Rx) CK clock high period	36.36	–	36.36	–	ns
17	(Tx/Rx) CK clock low period	36.36	–	36.36	–	ns
18	(Tx) CK high to FS (bl) high	10.22	17.63	8.82	16.24	ns
19	(Rx) CK high to FS (bl) high	10.79	19.67	9.39	18.28	ns

Table 31. SSI to SSI2 Ports Timing Parameters (Continued)

Ref No.	Parameter	1.8 V ± 0.1 V		3.0 V ± 0.3 V		Unit
		Minimum	Maximum	Minimum	Maximum	
11a	(Tx) CK high to STXD high	0.34	0.72	0.34	0.72	ns
11b	(Tx) CK high to STXD low	0.34	0.72	0.34	0.72	ns
12	(Tx) CK high to STXD high impedance	0.34	0.48	0.34	0.48	ns
13	SRXD setup time before (Rx) CK low	21.50	–	21.50	–	ns
14	SRXD hold time after (Rx) CK low	0	–	0	–	ns
External Clock Operation (SSI2 Ports)						
15	(Tx/Rx) CK clock period[1]	90.91	–	90.91	–	ns
16	(Tx/Rx) CK clock high period	36.36	–	36.36	–	ns
17	(Tx/Rx) CK clock low period	36.36	–	36.36	–	ns
18	(Tx) CK high to FS (bl) high	10.40	17.37	8.67	15.88	ns
19	(Rx) CK high to FS (bl) high	11.00	19.70	9.28	18.21	ns
20	(Tx) CK high to FS (bl) low	10.40	17.37	8.67	15.88	ns
21	(Rx) CK high to FS (bl) low	11.00	19.70	9.28	18.21	ns
22	(Tx) CK high to FS (wl) high	10.40	17.37	8.67	15.88	ns
23	(Rx) CK high to FS (wl) high	11.00	19.70	9.28	18.21	ns
24	(Tx) CK high to FS (wl) low	10.40	17.37	8.67	15.88	ns
25	(Rx) CK high to FS (wl) low	11.00	19.70	9.28	18.21	ns
26	(Tx) CK high to STXD valid from high impedance	9.59	17.08	7.86	15.59	ns
27a	(Tx) CK high to STXD high	9.59	17.08	7.86	15.59	ns
27b	(Tx) CK high to STXD low	9.59	17.08	7.86	15.59	ns
28	(Tx) CK high to STXD high impedance	9.59	16.84	7.86	15.35	ns
29	SRXD setup time before (Rx) CK low	2.52	–	2.52	–	ns
30	SRXD hole time after (Rx) CK low	0	–	0	–	ns
Synchronous Internal Clock Operation (SSI2 Ports)						
31	SRXD setup before (Tx) CK falling	20.78	–	20.78	–	ns
32	SRXD hold after (Tx) CK falling	0	–	0	–	ns
Synchronous External Clock Operation (SSI2 Ports)						
33	SRXD setup before (Tx) CK falling	4.42	–	4.42	–	ns
34	SRXD hold after (Tx) CK falling	0	–	0	–	ns

1. All the timings for the SSI are given for a non-inverted serial clock polarity (TSCKP/RSCKP = 0) and a non-inverted frame sync (TFSI/RFSI = 0). If the polarity of the clock and/or the frame sync have been inverted, all the timing remains valid by inverting the clock signal STCK/SRCK and/or the frame sync STFS/SRFS shown in the tables and in the figures.

Table 32. SSI to SSI3 Ports Timing Parameters (Continued)

Ref No.	Parameter	1.8 V ± 0.1 V		3.0 V ± 0.3 V		Unit
		Minimum	Maximum	Minimum	Maximum	
28	(Tx) CK high to STXD high impedance	9.02	16.46	7.29	14.97	ns
29	SRXD setup time before (Rx) CK low	1.49	–	1.49	–	ns
30	SRXD hole time after (Rx) CK low	0	–	0	–	ns
Synchronous Internal Clock Operation (SSI3 Ports)						
31	SRXD setup before (Tx) CK falling	21.99	–	21.99	–	ns
32	SRXD hold after (Tx) CK falling	0	–	0	–	ns
Synchronous External Clock Operation (SSI3 Ports)						
33	SRXD setup before (Tx) CK falling	3.80	–	3.80	–	ns
34	SRXD hold after (Tx) CK falling	0	–	0	–	ns

1. All the timings for the SSI are given for a non-inverted serial clock polarity (TSCKP/RSCKP = 0) and a non-inverted frame sync (TFSI/RFSI = 0). If the polarity of the clock and/or the frame sync have been inverted, all the timing remains valid by inverting the clock signal STCK/SRCK and/or the frame sync STFS/SRFS shown in the tables and in the figures.

3.16 1-Wire Interface Timing

3.16.1 Reset Sequence with Reset Pulse Presence Pulse

To begin any communications with the DS2502, it is required that an initialization procedure be issued. A reset pulse must be generated and then a presence pulse must be detected. The minimum reset pulse length is 480 us. The bus master (one-wire) will generate this pulse, then after the DS2502 detects a rising edge on the one-wire bus, it will wait 15-60 us before it will transmit back a presence pulse. The presence pulse will exist for 60-240 us.

The timing diagram for this sequence is shown in Figure 38.

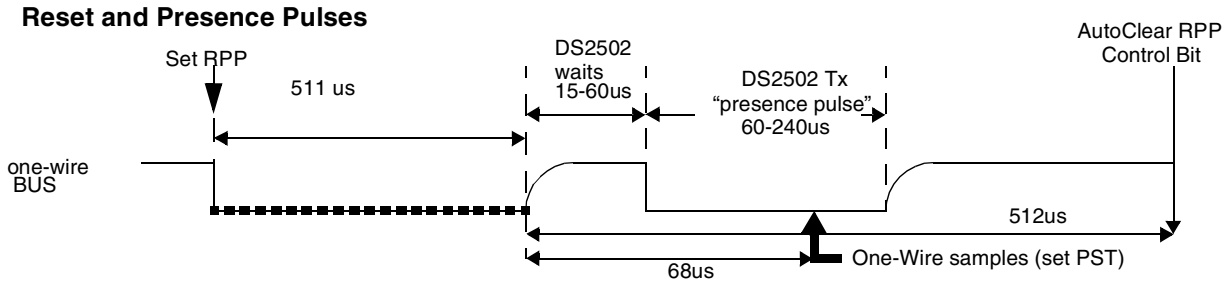


Figure 38. 1-Wire Initialization

The reset pulse begins the initialization sequence and it is initiated when the RPP control register bit is set. When the presence pulse is detected, this bit will be cleared. The presence pulse is used by the bus master to determine if at least one DS2502 is connected. Software will determine if more than one DS2502 exists. The one-wire will sample for the DS2502 presence pulse. The presence pulse is latched in the one-wire

3.17 USB On-The-Go

Four types of data transfer modes exist for the USB module: control transfers, bulk transfers, isochronous transfers and interrupt transfers. From the perspective of the USB module, the interrupt transfer type is identical to the bulk data transfer mode, and no additional hardware is supplied to support it. This section covers the transfer modes and how they work from the ground up.

Data moves across the USB in packets. Groups of packets are combined to form data transfers. The same packet transfer mechanism applies to bulk, interrupt, and control transfers. Isochronous data is also moved in the form of packets, but because isochronous pipes are given a fixed portion of the USB bandwidth at all times, there is no end-of-transfer.

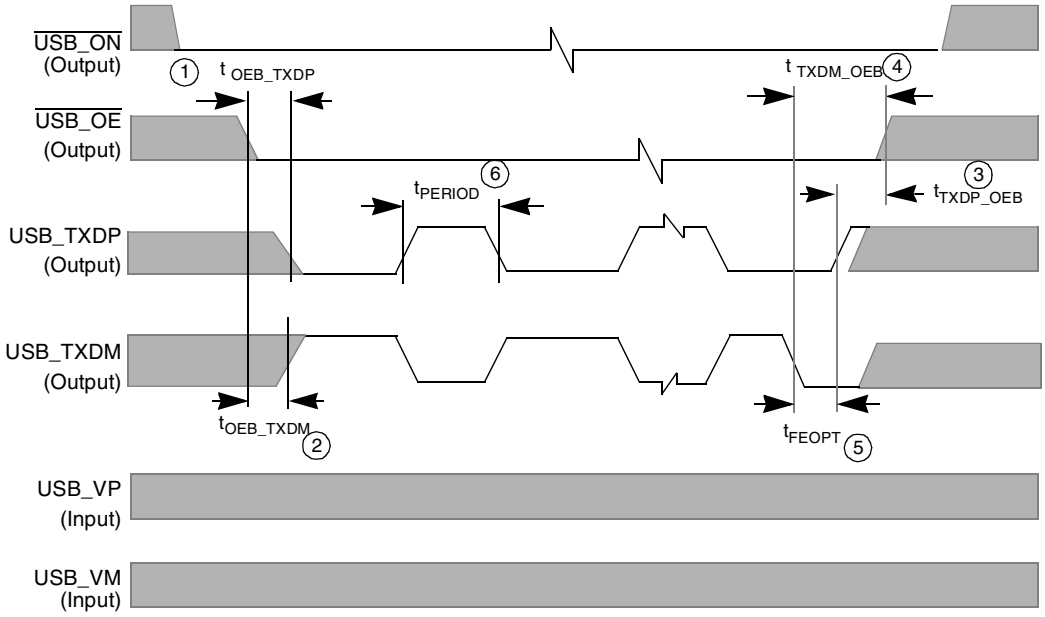


Figure 42. USB Timing Diagram for Data Transfer to USB Transceiver (TX)

Table 35. USB Timing Parameters for Data Transfer to USB Transceiver (TX)

Ref No.	Parameter	3.0 V ± 0.3 V		Unit
		Minimum	Maximum	
1	t_{OEB_TXDP}; $\overline{USBD\_OE}$ active to USBD_TXDP low	83.14	83.47	ns
2	t_{OEB_TXDM}; $\overline{USBD\_OE}$ active to USBD_TXDM high	81.55	81.98	ns
3	t_{TXDP_OEB}; USBD_TXDP high to $\overline{USBD\_OE}$ deactivated	83.54	83.8	ns
4	t_{TXDM_OEB}; USBD_TXDM low to $\overline{USBD\_OE}$ deactivated (includes SE0)	248.9	249.13	ns
5	t_{FEOPT}; SE0 interval of EOP	160	175	ns
6	t_{PERIOD}; Data transfer rate	11.97	12.03	Mb/s

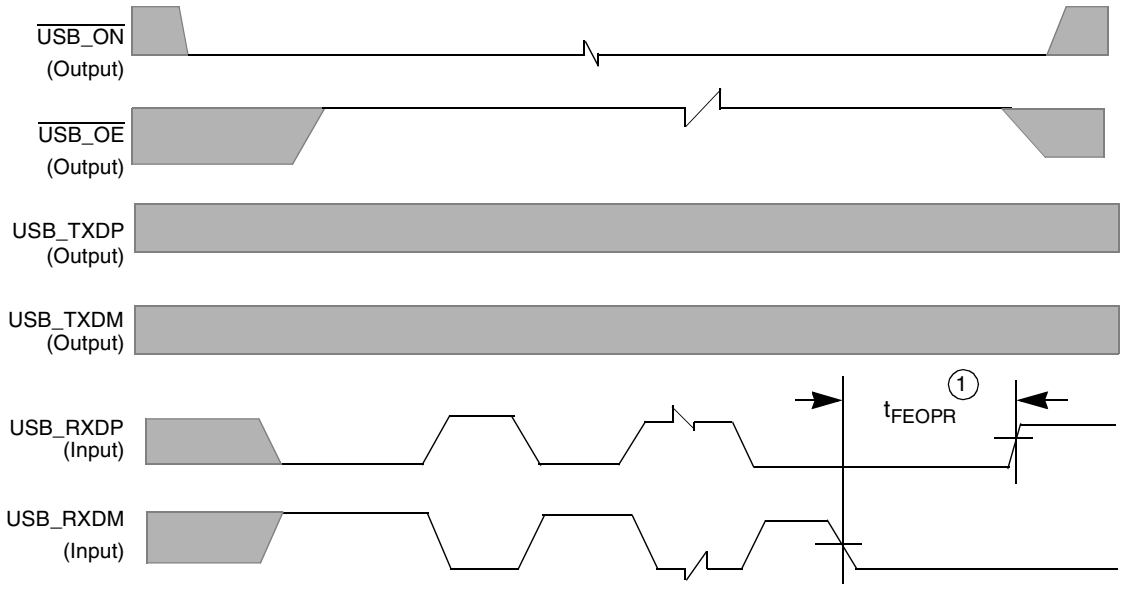


Figure 43. USB Timing Diagram for Data Transfer from USB Transceiver (RX)

Table 36. USB Timing Parameters for Data Transfer from USB Transceiver (RX)

Ref No.	Parameter	3.0 V ± 0.3 V		Unit
		Minimum	Maximum	
1	t_{FEOPR}; Receiver SE0 interval of EOP	82	–	ns

The USBOTG I^2C communication protocol consists of six components: START, Data Source/Recipient, Data Direction, Slave Acknowledge, Data, Data Acknowledge, and STOP.

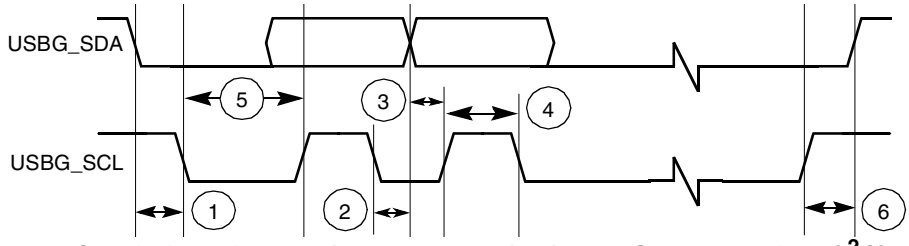


Figure 44. USB Timing Diagram for Data Transfer from USB Transceiver (I^2C)

Table 37. USB Timing Parameters for Data Transfer from USB Transceiver (I^2C)

Ref No.	Parameter	1.8 V ± 0.1 V		Unit
		Minimum	Maximum	
1	Hold time (repeated) START condition	188	–	ns
2	$\overline{\text{Data hold time}}$	0	188	ns
3	Data setup time	88	–	ns
4	HIGH period of the SCL clock	500	–	ns
5	LOW period of the SCL clock	500	–	ns
6	Setup time for STOP condition	185	–	ns

Note: Signals listed with lower case letters are internal to the device.

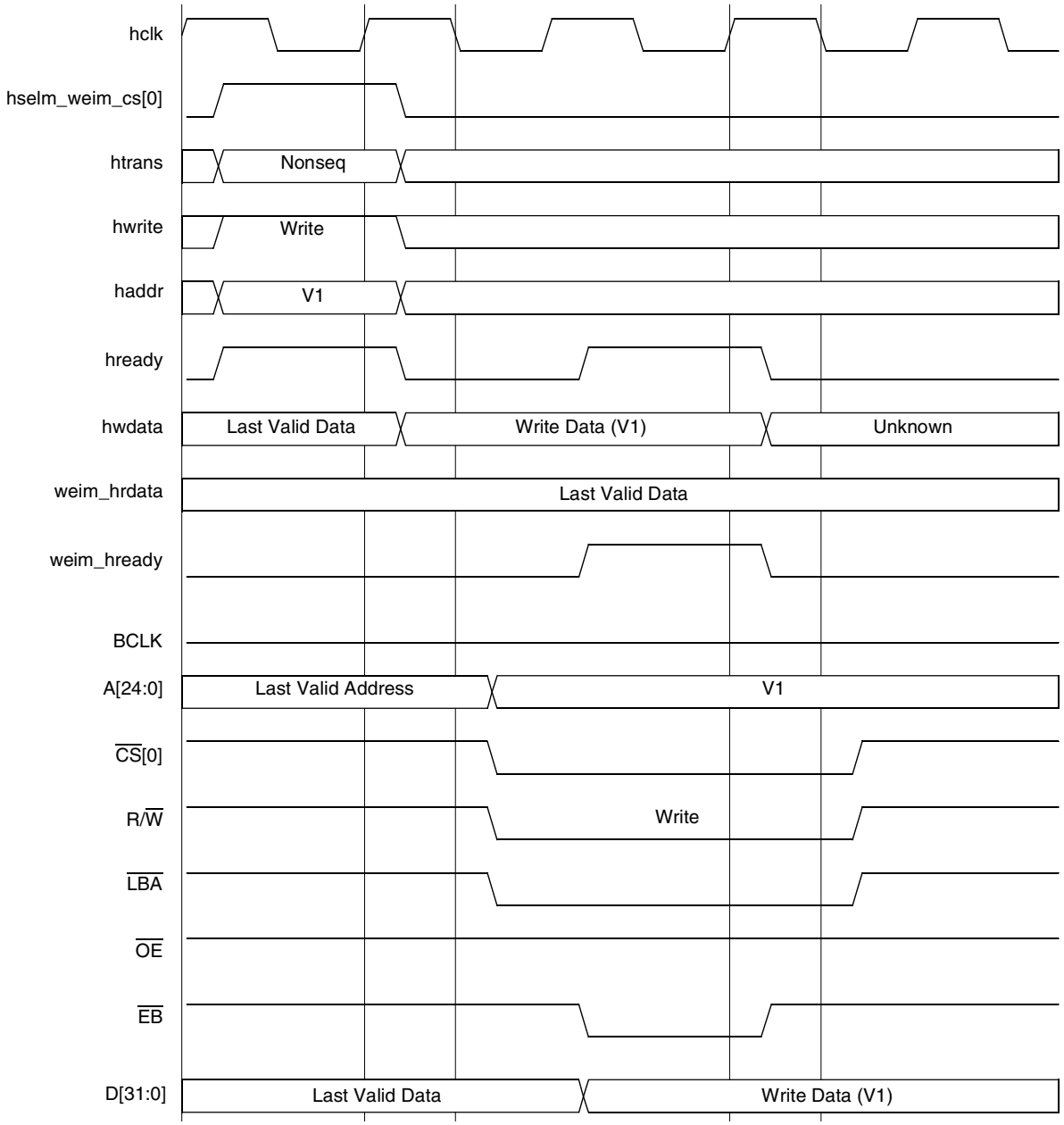


Figure 47. WSC = 1, WEA = 1, WEN = 1, A.HALF/E.HALF

Note: Signals listed with lower case letters are internal to the device.

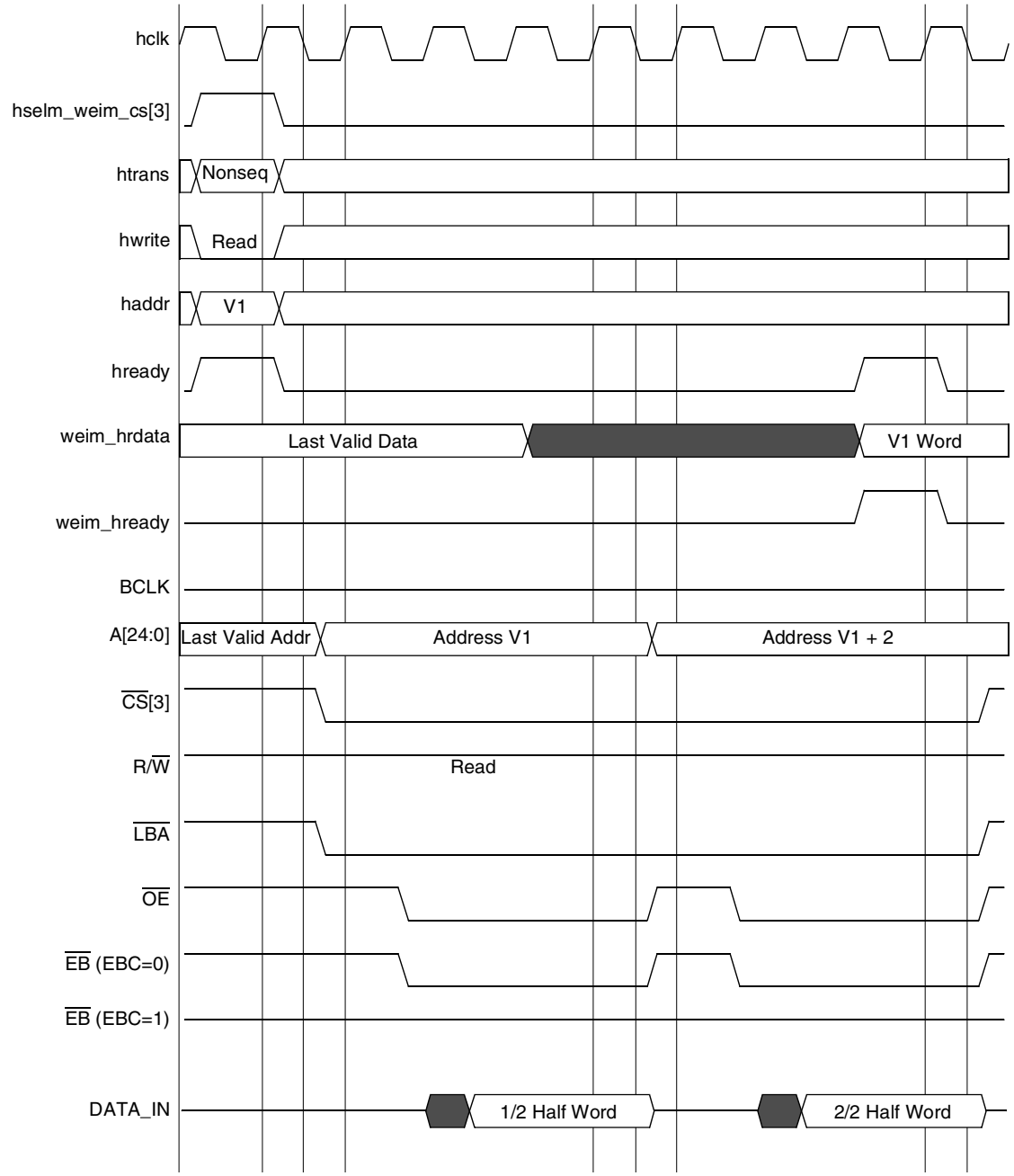


Figure 50. WSC = 3, OEA = 2, A.WORD/E.HALF

Note: Signals listed with lower case letters are internal to the device.

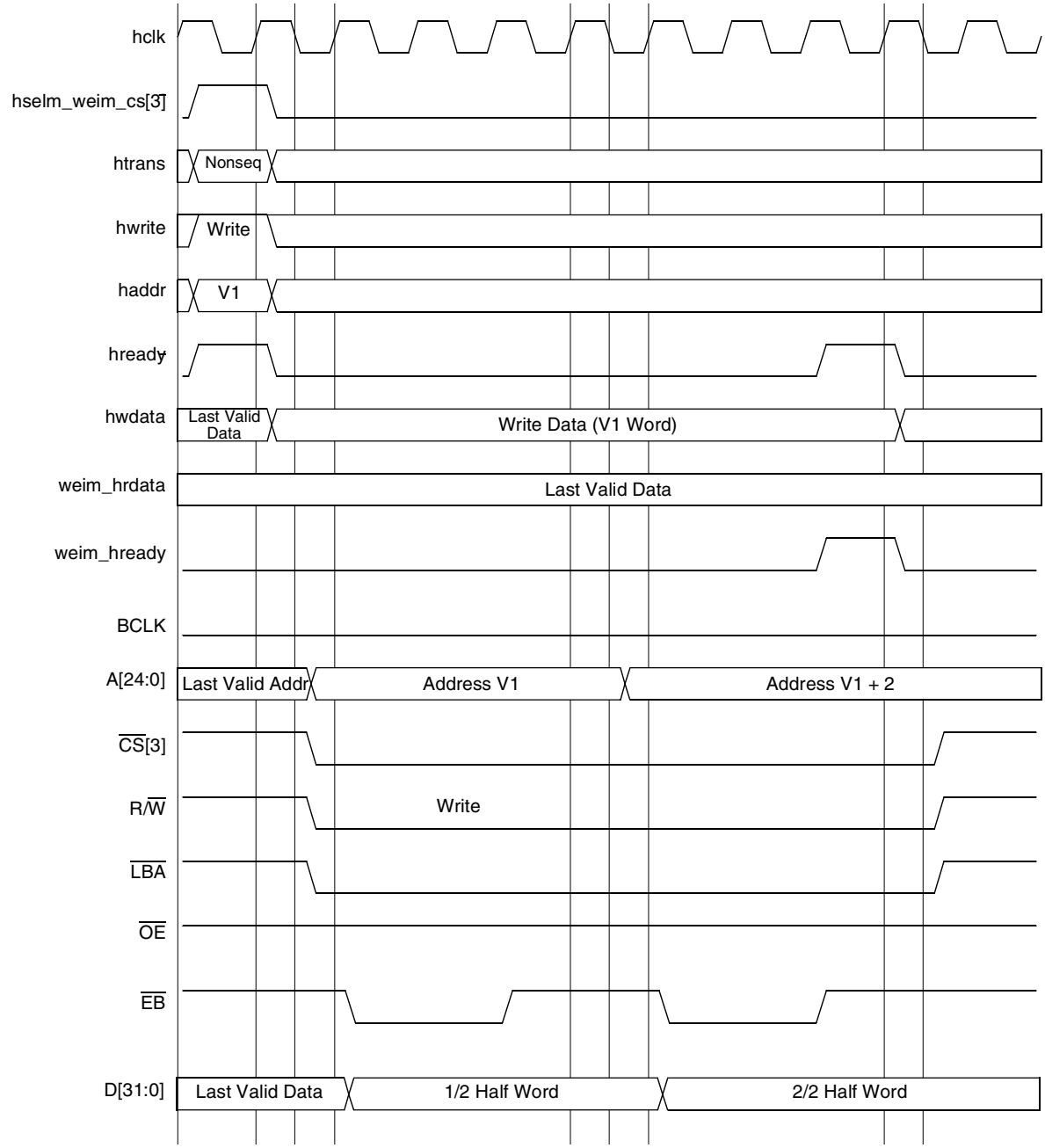


Figure 51. WSC = 3, WEA = 1, WEN = 3, A.WORD/E.HALF

Note: Signals listed with lower case letters are internal to the device.

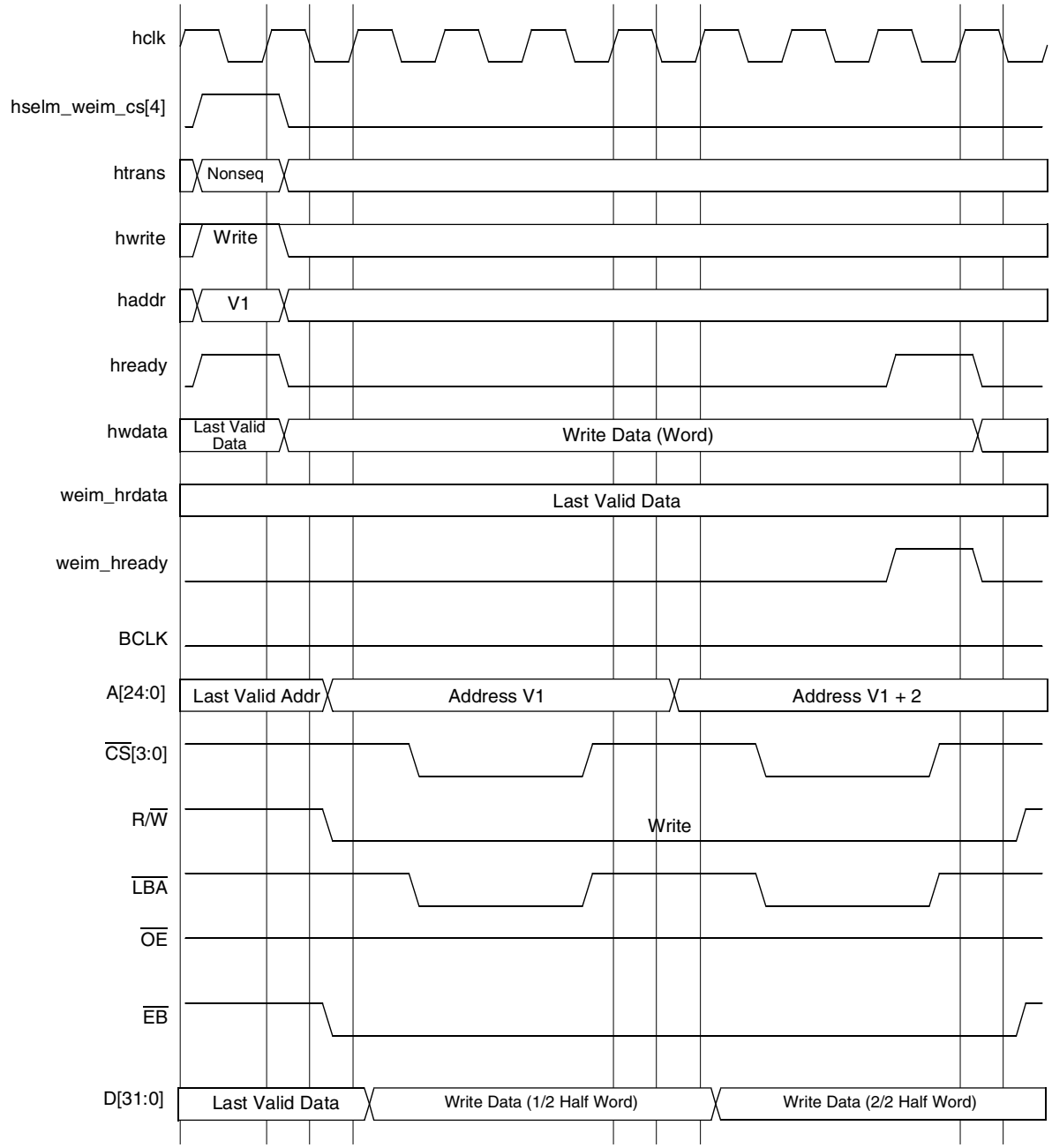


Figure 60. WSC = 2, CSA = 1, WWS = 1, A.WORD/E.HALF

Note: Signals listed with lower case letters are internal to the device.

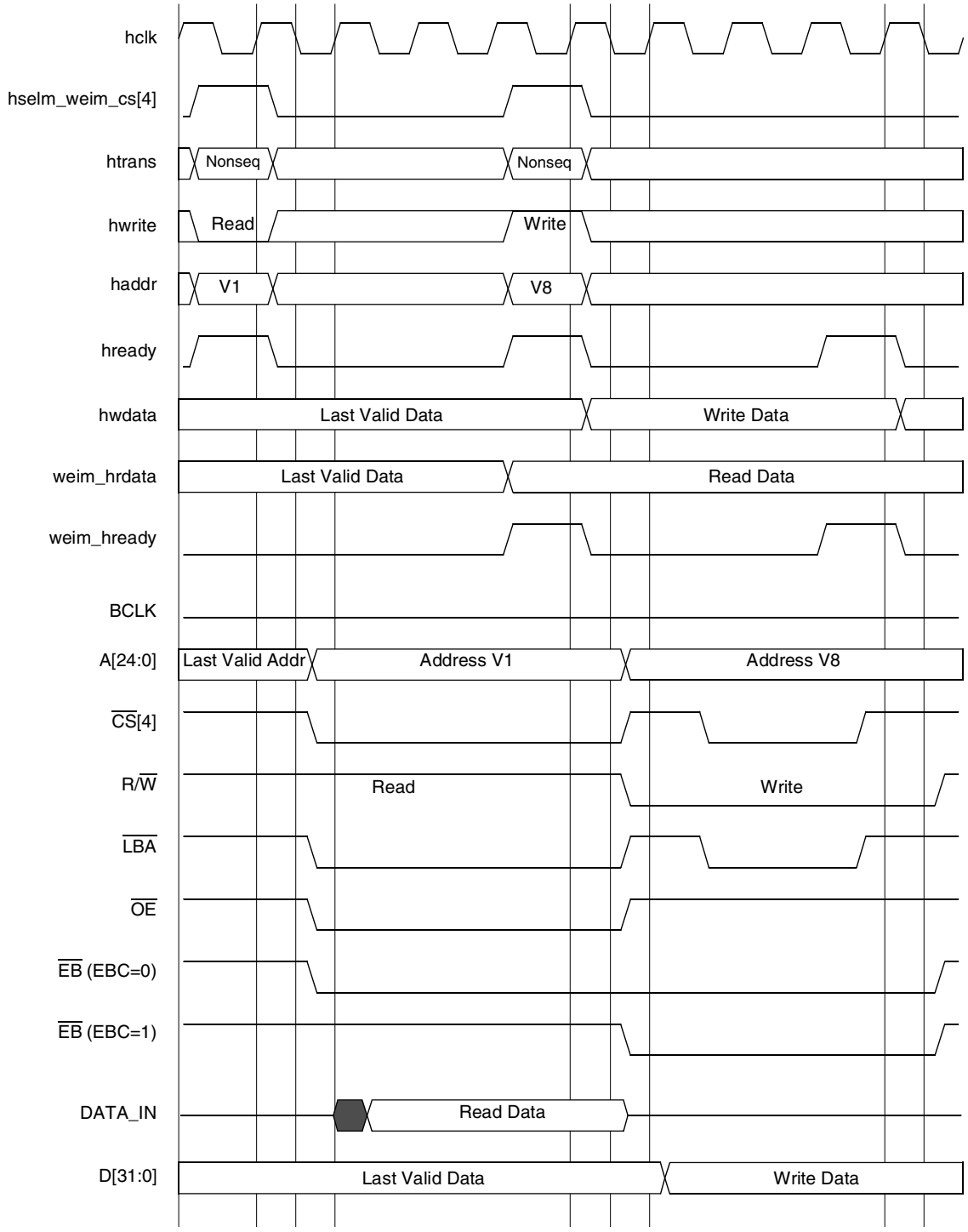


Figure 61. WSC = 3, CSA = 1, A.HALF/E.HALF

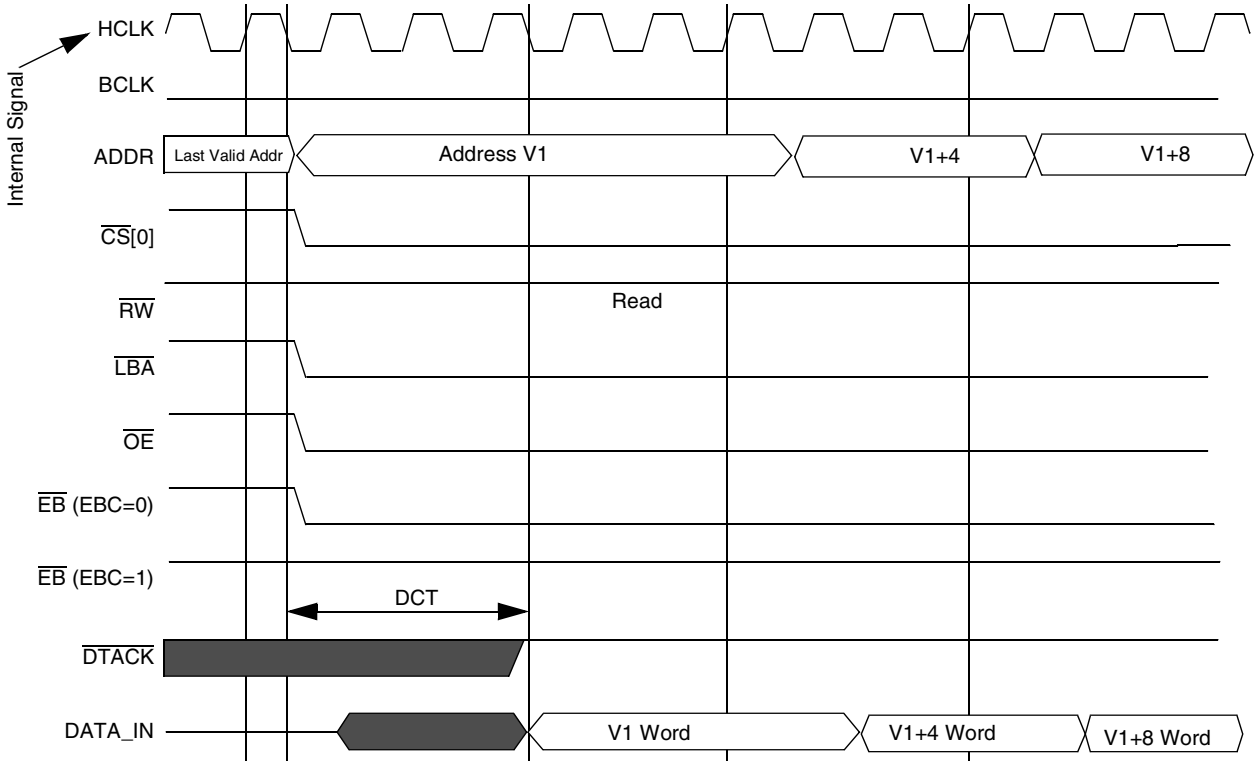


Figure 70. DTACK Level Sensitive Sequential Read Accesses, WSC=2, EW=1, DCT=1, AGE=0 (Example of DTACK Remaining High)

4 Pin Assignment and Package Information

Table 40. i.MX21S Pin Assignment

	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18	19
A	LD9	LD12	LD14	REV	HSYNC	OE_ ACD	SD2_D2	PB10	PB16	PB20	USBH1_ FS	USBH1_ OE	USBG_ FS	TOUT	SAP_ TXDAT	SSI1_ CLK	SSI2_ RXDAT	SSI2_TXDAT	SSI3_ FS
B	LD7	LD5	LD11	LD16	PS	CON TRAST	SD2_D0	SD2_ CMD	PB14	PB18	USB_ PWR	USBG_ SCL	USBG_ TXDM	SAP_ FS	SSI1_ FS	SSI2_ FS	SSI3_ TXDAT	I2C_DATA	CSPI2_ SS2
C	LD1	LD3	LD6	LD10	LD17	VSYNC	SD2_D3	PB11	PB15	PB21	USB_ OC	USBH1_ RXDM	USBG_ RXDM	TIN	SSI1_ TXDAT	SSI3_ RXDAT	SSI3_ CLK	I2C_CLK	CSPI2_ SS1
D	LD2	LD0	LD13	CLS	QVDD	QVSS	SD2_D1	SD2_ CLK	PB12	PB19	USBH1_ TXDM	USBH1_ RXDP	USBG_ ON	USBG_ RXDP	SAP_ RXDAT	SSI1_ RXDAT	SSI2_ CLK	CSPI2_SS0	CSPI2_ SCLK
E	LD8	LD4	LD15	SPL_ SPR												SAP_ CLK	CSPI2_ MISO	CSPI1_SS2	CSPI2_ MOSI
F	A24_ NFIO14	D31	A25_ NFIO15	LSCLK												CSPI1_ SS1	CSPI1_ MISO	KP_ROW0	CSPI1_ SS0
G	A22_ NFIO12	D29	A23_ NFIO13	D30			NVDD6	NVSS6	PB13	USB_ BYP	USBH_ ON	USBG_ SDA	USBG_ TXDP			KP_ ROW1	KP_ ROW3	PE3	KP_ ROW4
H	A20	D27	A21_ NFIO11	D28			NVDD1	NVSS5	PB17	CSPI1_ SCLK	CSPI1_ RDY	USBH1_ TXDP	USBG_ OE			TEST_ WB4	TEST_ WB2	TEST_WB3	PWMO
J	A19	A18	D25	D26			NVDD1	NVDD5	NVDD4	KP_ ROW5	KP_ ROW2	CSPI1_ MOSI	TEST_ WB0			PE4	KP_COL1	KP_COL0	TEST_ WB1
K	A16	A17	D23	D24			NVSS1	NVSS4	QVDDX	UART1_ RXD	TDO	QVDD	QVSS			KP_ COL3	KP_COL5	KP_COL4	KP_ COL2
L	A14_ NFIO9	A15_ NFIO10	D21	D22			NVSS1	NVDD3	QVDD	QVSS	NFIO2	NFWP	UART1_ TXD			PE6	UART3_ RTS	UART3_CTS	UART3_ TXD
M	D19	A13_ NFIO8	D20	D18			NVDD2	NVDD3	NVSS3	QVSS	NFIO7	NFRB	EXT_ 48M			PE7	UART3_ RXD	UART1_RTS	UART1_ CTS
N	A11	A12	D17	D16			LBA	NVSS3	SDCKE0	NVSS1	NVSS1	NVDD1	NVDD1			SD1_ D0	TCK	SD1_D1	RTCK
P	A9	A10	D15	D14												SD1_ D2	SD1_ CMD	TDI	TMS
R	A7	A8	D13	D12												SD1_ CLK	EXT_ 266M	NVSS2	TRST
T	A5	A6	EB3	D10	CS3	CS1	BCLK	MA11	RAS	CAS	NFIO5	NFIO3	NFWE	RESET_ IN	NFCE	BOOT1	SD1_D3	CLKMODE1	CLK MODE0
U	D11	EB1	EB2	OE	CS4	D6	ECB	D3	MA10	PC_ PWRON	PF16	NFIO4	NFIO1	NFALE	NFCLE	POR	BOOT2	BOOT3	XTAL32K
V	A4	EB0	D9	D8	CS5	D5	CS0	RW	D1	JTAG_ CTRL	SDWE	CLKO	NFIO6	QVSS	RESET_ OUT	BOOT0	OSC26M_ TEST	VDDA	EXTAL 32K
W	A3	A2	D7	A1	CS2	A0	D4	D2	D0	SDCLK	SDCKE1	NFIO0	NFRE	QVDD	QVSS	EXTAL 26M	XTAL26M	QVDD	QVSS

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Freescale Semiconductor
Technical Information Center, CH370
1300 N. Alma School Road
Chandler, Arizona 85224
+1-800-521-6274 or +1-480-768-2130
support@freescale.com

Europe, Middle East, and Africa:
Freescale Halbleiter Deutschland GmbH
Technical Information Center
Schatzbogen 7
81829 Muenchen, Germany
+44 1296 380 456 (English)
+46 8 52200080 (English)
+49 89 92103 559 (German)
+33 1 69 35 48 48 (French)
support@freescale.com

Japan:
Freescale Semiconductor Japan Ltd.
Headquarters
ARCO Tower 15F
1-8-1, Shimo-Meguro, Meguro-ku,
Tokyo 153-0064, Japan
0120 191014 or +81 3 5437 9125
support.japan@freescale.com

Asia/Pacific:
Freescale Semiconductor Hong Kong Ltd.
Technical Information Center
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